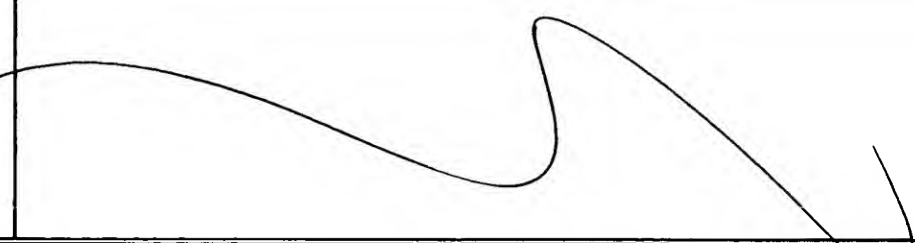
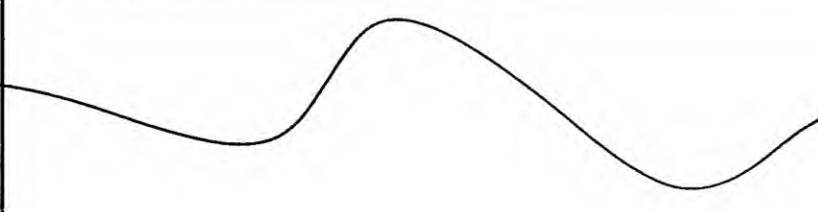


INFORMATION DISCLOSURE STATEMENT PTO-1449	Atty. Docket No.: 030112	Serial No.: New Appln. 10/714,858
	Applicant: Bor-Jen WU	
	Filing Date: November 18, 2003	Group Art Unit: ²⁸⁹¹ Not yet Assigned

U.S. PATENT DOCUMENTS

Examiner Initial	Document No.	Name	Date	Class	Subclass	Filing Date (If appropriate)
_____	AA					
_____	AB					
_____	AC					
_____	AD					
_____	AE					

FOREIGN PATENT DOCUMENTS

Document No.	Date	Country	Translation (Yes or No)
_____	AF		
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_____	AI		
_____	AJ		

OTHER DOCUMENTS

_____ <i>CME</i>	AK	L. C. Wang, et al. "Low Temperature-Processed (150-175°C) Ge/Pd-Based Ohmic Contacts ($\rho_c \sim 1 \times 10^{-6} \Omega \text{ cm}^2$) to η -GaAs" - Appl. Phys. Lett., pp. 67 - July 24, 1995	
_____	AL		
Examiner	<i>C. Juerkett</i>	Date Considered	<i>9-12-05</i>